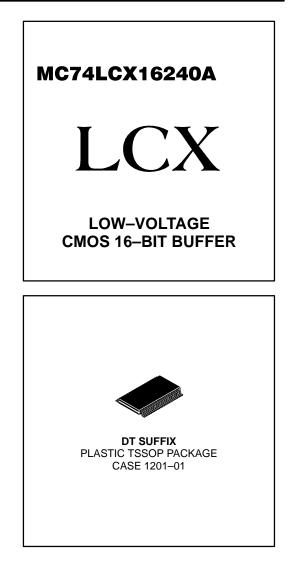
Low-Voltage CMOS 16-Bit Buffer With 5V-Tolerant Inputs and Outputs (3-State, Inverting)

The MC74LCX16240A is a high performance, inverting 16–bit buffer operating from a 2.7 to 3.6V supply. The device is nibble controlled. Each nibble has separate Output Enable inputs which can be tied together for full 16–bit operation. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5V allows MC74LCX16240A inputs to be safely driven from 5V devices. The LCX16240A is suitable for memory address driving and all TTL level bus oriented transceiver applications.

<u>Cu</u>rrent drive capability is 24mA at the outputs. The Output Enable (OEn) inputs, when HIGH, disable the outputs by placing them in a HIGH Z condition.

- Designed for 2.7 to 3.6V V_{CC} Operation
- 4.9ns Maximum t_{pd}
- 5V Tolerant Interface Capability With 5V TTL Logic
- · Supports Live Insertion and Withdrawal
- IOFF Specification Guarantees High Impedance When VCC = 0V
- JEDEC Standard JESD–36 Compatible
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (20μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

The MC74LCX16240A contains sixteen inverting buffers with 3–state 5V–tolerant outputs. The device is nibble controlled with each nibble functioning identically, but independently. The control pins may be tied together to obtain full <u>16–b</u>it operation. The 3–state outp<u>uts are controlled</u> by an Output Enable (OE<u>n) inp</u>ut for each nibble. When OEn is LOW, the outputs are on. When OEn is HIGH, the outputs are in the high impedance state.



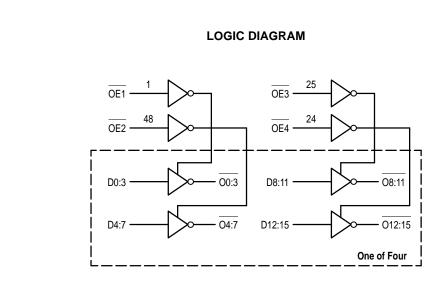
PIN NAMES

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Pins	Function
OEn	Output Enable Inputs
<u>D0</u> – <u>D15</u>	Inputs
O0–O15	Outputs



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		$\overline{}$	 1	
OE1 1	0	Ŭ	48	OE2
00 2			47	D0
01 3			46	D1
GND 4			45	GND
O2 5			44	D2
O3 6			43	D3
V _{CC} 7			42	VCC
O4 8			41	D4
O5 9			40	D5
GND 10			39	GND
06 11			38	D6
07 12			37	D7
O8 13			36	D8
09 14			35	D9
GND 15			34	GND
O10 16			33	D10
011 17			32	D11
V _{CC} 18			31	Vcc
012 19			30	D12
O13 20			29	D13
GND 21			28	GND
014 22			27	D14
015 23			26	D15
OE4 24			25	OE3
			I	

OE1	D0:3	00:3	OE2	D4:7	04:7	OE3	D8:11	08:11	OE4	D12:15	012:15
L	L	Н	L	L	Н	L	L	Н	L	L	Н
L	Н	L	L	Н	L	L	Н	L	L	Н	L
Н	Х	Z	Н	Х	Z	Н	Х	Z	н	Х	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions Are Acceptable, for I_{CC} reasons, DO NOT FLOAT Inputs

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
VCC	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \le V_{l} \le +7.0$		V
VO	DC Output Voltage	$-0.5 \le V_O \le +7.0$	Output in 3–State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Note 1.	V
liк	DC Input Diode Current	-50	V _I < GND	mA
юк	DC Output Diode Current	-50	V _O < GND	mA
		+50	VO > ACC	mA
IO	DC Output Source/Sink Current	±50		mA
ICC	DC Supply Current Per Supply Pin	±100		mA
I _{GND}	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied. 1. Output in HIGH or LOW State. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
VI	Input Voltage	0		5.5	V
VO	Output Voltage (HIGH or LOW State) (3–State)	0 0		V _{CC} 5.5	V
^I ОН	HIGH Level Output Current, $V_{CC} = 3.0V - 3.6V$			-24	mA
lol	LOW Level Output Current, $V_{CC} = 3.0V - 3.6V$			24	mA
^I ОН	HIGH Level Output Current, $V_{CC} = 2.7V - 3.0V$			-12	mA
lol	LOW Level Output Current, $V_{CC} = 2.7V - 3.0V$			12	mA
TA	Operating Free–Air Temperature	-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, V _{IN} from 0.8V to 2.0V, V _{CC} = $3.0V$	0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			T _A = −40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
VIH	HIGH Level Input Voltage (Note 2.)	$2.7V \le V_{CC} \le 3.6V$	2.0		V
VIL	LOW Level Input Voltage (Note 2.)	$2.7 \text{V} \leq \text{V}_{CC} \leq 3.6 \text{V}$		0.8	V
VOH	HIGH Level Output Voltage	$2.7V \leq V_{CC} \leq 3.6V; \ I_{OH} = -100 \mu A$	V _{CC} – 0.2		V
		$V_{CC} = 2.7V; I_{OH} = -12mA$	2.2		
		$V_{CC} = 3.0V; I_{OH} = -18mA$	2.4		
		$V_{CC} = 3.0V; I_{OH} = -24mA$	2.2		
VOL	LOW Level Output Voltage	$2.7V \leq V_{CC} \leq 3.6V; \ I_{OL} = 100 \mu A$		0.2	V
		V _{CC} = 2.7V; I _{OL} = 12mA		0.4	
		V _{CC} = 3.0V; I _{OL} = 16mA		0.4	
		V _{CC} = 3.0V; I _{OL} = 24mA		0.55	

2. These values of V₁ are used to test DC electrical characteristics only.

MC74LCX16240A

DC ELECTRICAL CHARACTERISTICS (continued)

			T _A = −40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
Ц	Input Leakage Current	$2.7V \leq V_{CC} \leq 3.6V; \ 0V \leq V_I \leq 5.5V$		±5.0	μΑ
loz	3-State Output Current	$\begin{array}{c} 2.7 \leq V_{CC} \leq 3.6 \text{V}; \ 0 \text{V} \leq \text{V}_{O} \leq 5.5 \text{V}; \\ \text{V}_{I} = \text{V}_{IH} \ \text{or} \ \text{V} \ \text{IL} \end{array}$		±5.0	μΑ
IOFF	Power–Off Leakage Current	$V_{CC} = 0V; V_I \text{ or } V_O = 5.5V$		10	μA
ICC	Quiescent Supply Current	$2.7 \leq V_{CC} \leq 3.6 \text{V}; \ \text{V}_{I} = \text{GND} \ \text{or} \ \text{V}_{CC}$		20	μΑ
		$2.7 \leq V_{CC} \leq 3.6 \textrm{V}; \ 3.6 \leq \textrm{V}_{I} \ \textrm{or} \ \textrm{V}_{O} \leq 5.5 \textrm{V}$		±20	μA
ΔICC	Increase in I _{CC} per Input	$2.7 \leq V_{CC} \leq 3.6 \text{V}; \text{ V}_{IH} = V_{CC} - 0.6 \text{V}$		500	μA

AC CHARACTERISTICS ($t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$)

				Limits			
			Т	T _A = −40°C to +85°C		1	
			V _{CC} = 3.	0V to 3.6V	V _{CC} = 2.7V	1	
Symbol	Parameter	Waveform	Min	Max	Мах	Unit	
^t PLH ^t PHL	Propagation Delay Input to Output	1	1.5 1.5	4.9 4.9	5.9 5.9	ns	
^t PZH ^t PZL	Output Enable Time to High and Low Level	2	1.5 1.5	6.5 6.5	7.5 7.5	ns	
^t PHZ ^t PLZ	Output Disable Time From High and Low Level	2	1.5 1.5	5.5 5.5	6.5 6.5	ns	
^t OSHL ^t OSLH	Output-to-Output Skew (Note 3.)			1.0 1.0		ns	

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

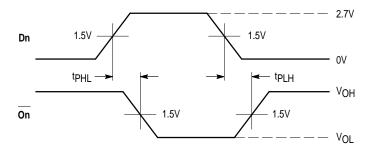
DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
VOLP	Dynamic LOW Peak Voltage (Note 4.)	$V_{\mbox{\scriptsize CC}}$ = 3.3V, $C_{\mbox{\scriptsize L}}$ = 50pF, $V_{\mbox{\scriptsize IH}}$ = 3.3V, $V_{\mbox{\scriptsize IL}}$ = 0V		0.8		V
V _{OLV}	Dynamic LOW Valley Voltage (Note 4.)	V_{CC} = 3.3V, C_L = 50pF, V_{IH} = 3.3V, V_{IL} = 0V		0.8		V

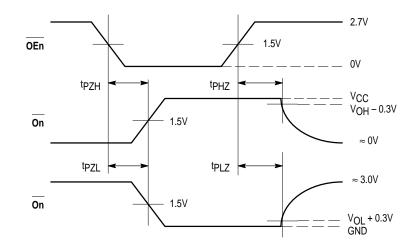
4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 3.3$ V, $V_{I} = 0$ V or V_{CC}	7	pF
COUT	Output Capacitance	$V_{CC} = 3.3$ V, $V_{I} = 0$ V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10MHz, V_{CC} = 3.3V, V_{I} = 0V or V_{CC}	20	pF

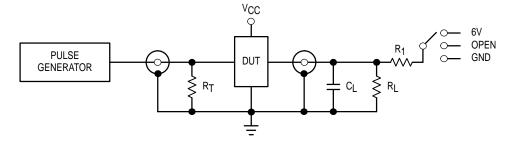


WAVEFORM 1 - PROPAGATION DELAYS $t_R = t_F = 2.5ns$, 10% to 90%; f = 1MHz; $t_W = 500ns$



WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1MHz; $t_W = 500$ ns





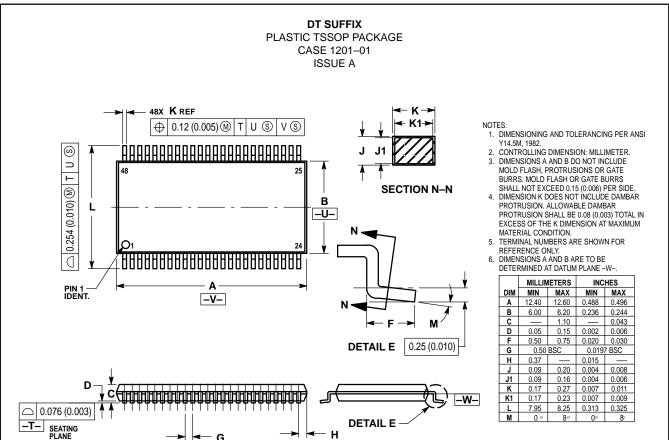
TEST	SWITCH
^t PLH ^{, t} PHL	Open
tPZL, tPLZ	6V
Open Collector/Drain tPLH and tPHL	6V
^t PZH ^{, t} PHZ	GND

 C_L = 50pF or equivalent (Includes jig and probe capacitance) R_L = R_1 = 500 Ω or equivalent

 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 2. Test Circuit

OUTLINE DIMENSIONS



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ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

